2SK2097

Silicon N-Channel MOS FET

HITACHI

November 1996

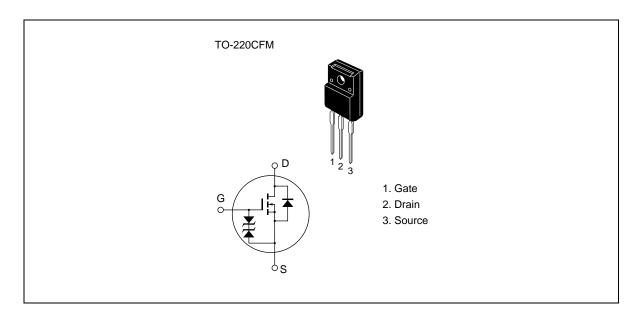
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No Secondary Breakdown
- Suitable for Switching regulator, DC DC converter.

Outline



2SK2097

Absolute Maximum Ratings $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	600	V
Gate to source voltage	V _{gss}	±30	V
Drain current	I _D	4	A
Drain peak current	h *1 D(pulse)	16	A
Body to drain diode reverse drain current	I _{DR}	4	A
Channel dissipation	Pch*2	35	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes 1. PW \leq 10 μ s, duty cycle \leq 1 %

2. Value at $Tc = 25^{\circ}C$

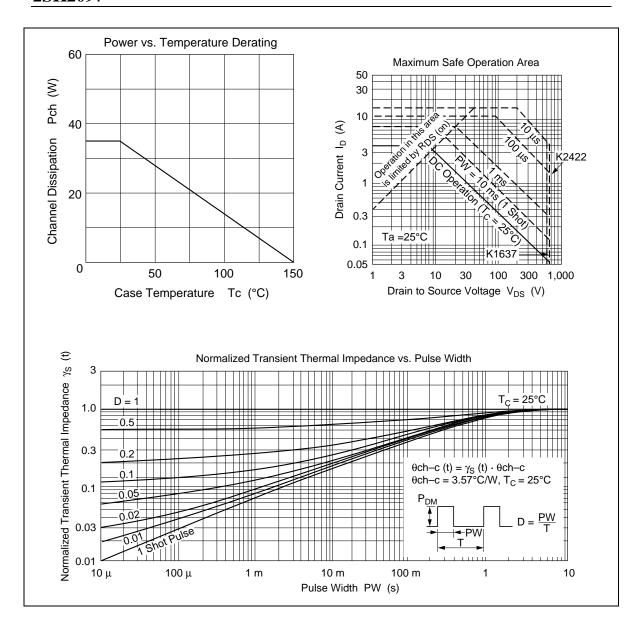
Electrical Characteristics ($Ta = 25^{\circ}C$)

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	_	_	V	$I_{D} = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±30	_	_	V	$I_{g} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	: I _{DSS}	_	_	250	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	_	3.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{\scriptscriptstyle DS(on)}$	_	1.8	2.4	Ω	$I_D = 2 A$ $V_{GS} = 10 V^{*1}$
Forward transfer admittance	y _{fs}	2.2	3.5	_	S	$I_{D} = 2 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	Ciss	_	600	_	pF	$V_{DS} = 10 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	Coss	_	140	_	pF	_
Reverse transfer capacitance	Crss	_	25	_	pF	_
Turn-on delay time	$\mathbf{t}_{\text{d(on)}}$	_	8	_	ns	$I_{D} = 2 A$ $V_{GS} = 10 V$ $R_{L} = 15\Omega$
Rise time	t _r	_	30	_	ns	
Turn-off delay time	$\mathbf{t}_{\text{d(off)}}$	_	60	_	ns	
Fall time	t _f	_	35	_	ns	_
Body to drain diode forward voltage	V_{DF}	_	0.9		V	$I_{F} = 4 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t _{rr}	_	300	_	ns	$I_F = 4 \text{ A}, V_{GS} = 0,$ diF / dt = 100 A / μ s

Note 1. Pulse Test

See characteristic curve of 2SK1402.

2SK2097



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